NSN 5961-00-477-1649

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-477-1649 **Inclosure Material:** Metal **Overall Length:** 0.565 inches **Overall Height:** 0.565 inches **Overall Diameter:** 1.650 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 900.0 breakover voltage, dc **Current Rating Per Characteristic:** 175.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 120.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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